

# PNP - 2N6040, 2N6042, NPN - 2N6043, 2N6045

2N6043 and 2N6045 are Preferred Devices

## Plastic Medium-Power Complementary Silicon Transistors

Plastic medium-power complementary silicon transistors are designed for general-purpose amplifier and low-speed switching applications.

### Features

- High DC Current Gain -  $h_{FE} = 2500$  (Typ) @  $I_C = 4.0$  Adc
- Collector-Emitter Sustaining Voltage - @ 100 mAdc -  
 $V_{CE(sus)} = 60$  Vdc (Min) - 2N6040, 2N6043  
 $= 100$  Vdc (Min) - 2N6042, 2N6045
- Low Collector-Emitter Saturation Voltage -  
 $V_{CE(sat)} = 2.0$  Vdc (Max) @  $I_C = 4.0$  Adc - 2N6043, 44  
 $= 2.0$  Vdc (Max) @  $I_C = 3.0$  Adc - 2N6042, 2N6045
- Monolithic Construction with Built-In Base-Emitter Shunt Resistors
- Epoxy Meets UL 94 V-0 @ 0.125 in
- ESD Ratings: Human Body Model, 3B > 8000 V  
Machine Model, C > 400 V
- Pb-Free Packages are Available\*

### MAXIMUM RATINGS (Note 1)

Rating	Symbol	Value	Unit
Collector-Emitter Voltage	$V_{CEO}$	60	Vdc
		100	
Collector-Base Voltage	$V_{CB}$	60	Vdc
		100	
Emitter-Base Voltage	$V_{EB}$	5.0	Vdc
Collector Current	$I_C$	8.0	Adc
		16	
Base Current	$I_B$	120	mAdc
Total Power Dissipation @ $T_C = 25^\circ\text{C}$ Derate above $25^\circ\text{C}$	$P_D$	75 0.60	W W/ $^\circ\text{C}$
Operating and Storage Junction Temperature Range	$T_J, T_{stg}$	-65 to +150	$^\circ\text{C}$

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. Indicates JEDEC Registered Data.

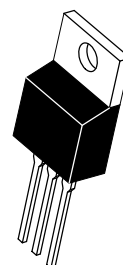
\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.



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## DARLINGTON, 8 AMPERES COMPLEMENTARY SILICON POWER TRANSISTORS 60 - 100 VOLTS, 75 WATTS



TO-220AB  
CASE 221A-09  
STYLE 1

### MARKING DIAGRAM



2N604x = Device Code  
x = 0, 2, 3, or 5  
A = Assembly Location  
Y = Year  
WW = Work Week  
G = Pb-Free Package

### ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 5 of this data sheet.

**Preferred** devices are recommended choices for future use and best overall value.

# PNP – 2N6040, 2N6042, NPN – 2N6043, 2N6045

## THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction-to-Case	$\theta_{JC}$	1.67	°C/W
Thermal Resistance, Junction-to-Ambient	$\theta_{JA}$	57	°C/W

## \*ELECTRICAL CHARACTERISTICS ( $T_C = 25^\circ\text{C}$ unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
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### OFF CHARACTERISTICS

Collector-Emitter Sustaining Voltage ( $I_C = 100\text{ mAdc}$ , $I_B = 0$ )	2N6040, 2N6043 2N6042, 2N6045	$V_{CE(sus)}$	60 100	– –	Vdc
Collector Cutoff Current ( $V_{CE} = 60\text{ Vdc}$ , $I_B = 0$ ) ( $V_{CE} = 100\text{ Vdc}$ , $I_B = 0$ )	2N6040, 2N6043 2N6042, 2N6045	$I_{CEO}$	– –	20 20	$\mu\text{A}$
Collector Cutoff Current ( $V_{CE} = 60\text{ Vdc}$ , $V_{BE(off)} = 1.5\text{ Vdc}$ ) ( $V_{CE} = 100\text{ Vdc}$ , $V_{BE(off)} = 1.5\text{ Vdc}$ ) ( $V_{CE} = 60\text{ Vdc}$ , $V_{BE(off)} = 1.5\text{ Vdc}$ , $T_C = 150^\circ\text{C}$ ) ( $V_{CE} = 80\text{ Vdc}$ , $V_{BE(off)} = 1.5\text{ Vdc}$ , $T_C = 150^\circ\text{C}$ ) ( $V_{CE} = 100\text{ Vdc}$ , $V_{BE(off)} = 1.5\text{ Vdc}$ , $T_C = 150^\circ\text{C}$ )	2N6040, 2N6043 2N6042, 2N6045 2N6040, 2N6043 2N6041, 2N6044 2N6042, 2N6045	$I_{CEX}$	– – – – –	20 20 200 200 200	$\mu\text{A}$
Collector Cutoff Current ( $V_{CB} = 60\text{ Vdc}$ , $I_E = 0$ ) ( $V_{CB} = 100\text{ Vdc}$ , $I_E = 0$ )	2N6040, 2N6043 2N6042, 2N6045	$I_{CBO}$	– –	20 20	$\mu\text{A}$
Emitter Cutoff Current ( $V_{BE} = 5.0\text{ Vdc}$ , $I_C = 0$ )		$I_{EBO}$	–	2.0	mAdc

### ON CHARACTERISTICS

DC Current Gain ( $I_C = 4.0\text{ Adc}$ , $V_{CE} = 4.0\text{ Vdc}$ ) ( $I_C = 3.0\text{ Adc}$ , $V_{CE} = 4.0\text{ Vdc}$ ) ( $I_C = 8.0\text{ Adc}$ , $V_{CE} = 4.0\text{ Vdc}$ )	2N6040, 2N6043, 2N6042, 2N6045 All Types	$h_{FE}$	1000 1000 100	20.000 20,000 –	–
Collector-Emitter Saturation Voltage ( $I_C = 4.0\text{ Adc}$ , $I_B = 16\text{ mAdc}$ ) ( $I_C = 3.0\text{ Adc}$ , $I_B = 12\text{ mAdc}$ ) ( $I_C = 8.0\text{ Adc}$ , $I_B = 80\text{ Adc}$ )	2N6040, 2N6043, 2N6042, 2N6045 All Types	$V_{CE(sat)}$	– – –	2.0 2.0 4.0	Vdc
Base-Emitter Saturation Voltage ( $I_C = 8.0\text{ Adc}$ , $I_B = 80\text{ mAdc}$ )		$V_{BE(sat)}$	–	4.5	Vdc
Base-Emitter On Voltage ( $I_C = 4.0\text{ Adc}$ , $V_{CE} = 4.0\text{ Vdc}$ )		$V_{BE(on)}$	–	2.8	Vdc

### DYNAMIC CHARACTERISTICS

Small Signal Current Gain ( $I_C = 3.0\text{ Adc}$ , $V_{CE} = 4.0\text{ Vdc}$ , $f = 1.0\text{ MHz}$ )		$ h_{fe} $	4.0	–	
Output Capacitance ( $V_{CB} = 10\text{ Vdc}$ , $I_E = 0$ , $f = 0.1\text{ MHz}$ )	2N6040/2N6042 2N6043/2N6045	$C_{ob}$	– –	300 200	pF
Small-Signal Current Gain ( $I_C = 3.0\text{ Adc}$ , $V_{CE} = 4.0\text{ Vdc}$ , $f = 1.0\text{ kHz}$ )		$h_{fe}$	300	–	–

\*Indicates JEDEC Registered Data.

# PNP – 2N6040, 2N6042, NPN – 2N6043, 2N6045

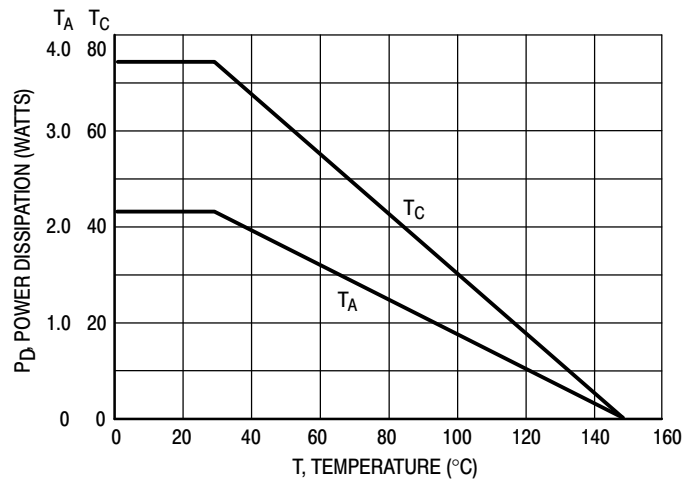


Figure 1. Power Derating

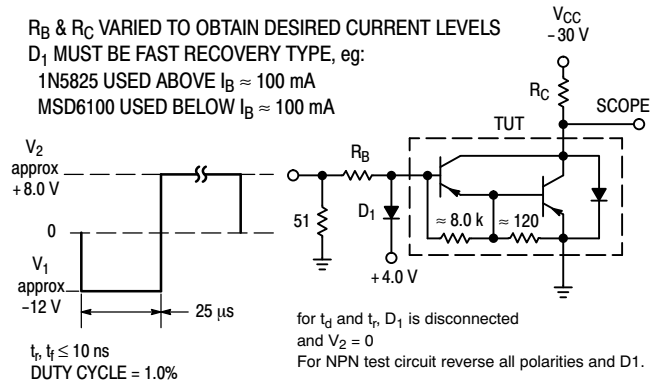


Figure 2. Switching Times Equivalent Circuit

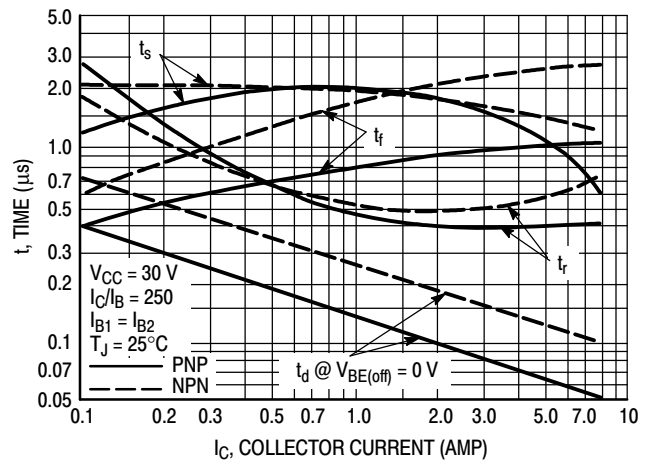


Figure 3. Switching Times

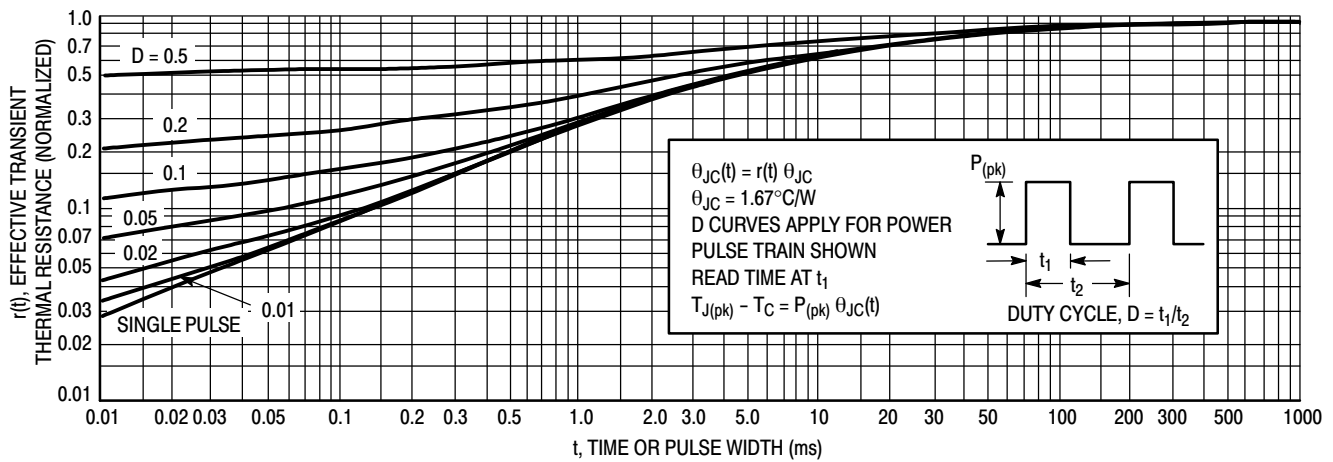


Figure 4. Thermal Response

## PNP – 2N6040, 2N6042, NPN – 2N6043, 2N6045

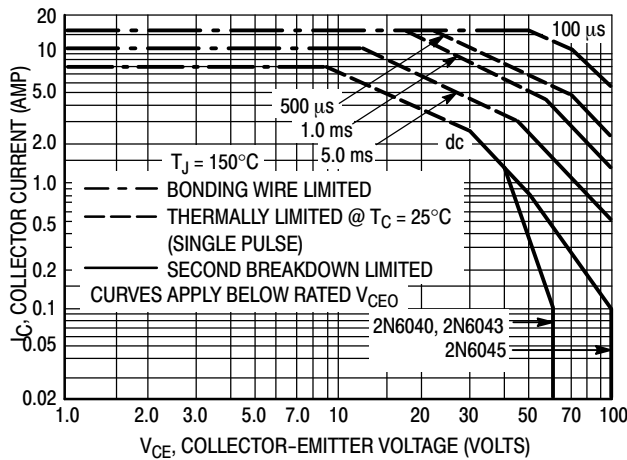


Figure 5. Active-Region Safe Operating Area

There are two limitations on the power handling ability of a transistor: average junction temperature and second breakdown. Safe operating area curves indicate  $I_C - V_{CE}$  limits of the transistor that must be observed for reliable operation; i.e., the transistor must not be subjected to greater dissipation than the curves indicate.

The data of Figure 5 is based on  $T_{J(pk)} = 150^\circ\text{C}$ ;  $T_C$  is variable depending on conditions. Second breakdown pulse limits are valid for duty cycles to 10% provided  $T_{J(pk)} < 150^\circ\text{C}$ .  $T_{J(pk)}$  may be calculated from the data in Figure 4. At high case temperatures, thermal limitations will reduce the power that can be handled to values less than the limitations imposed by second breakdown.

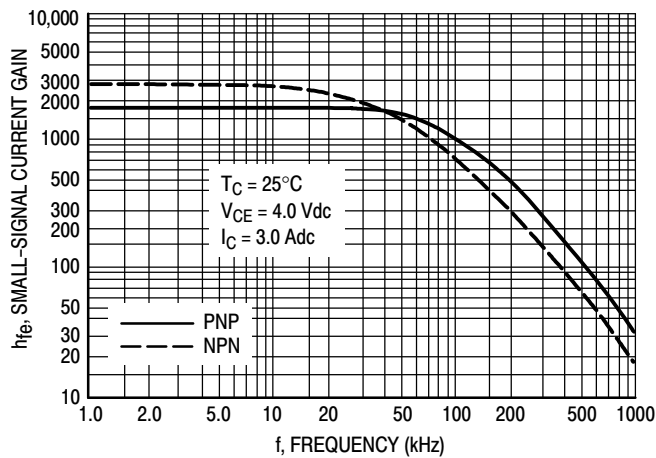


Figure 6. Small-Signal Current Gain

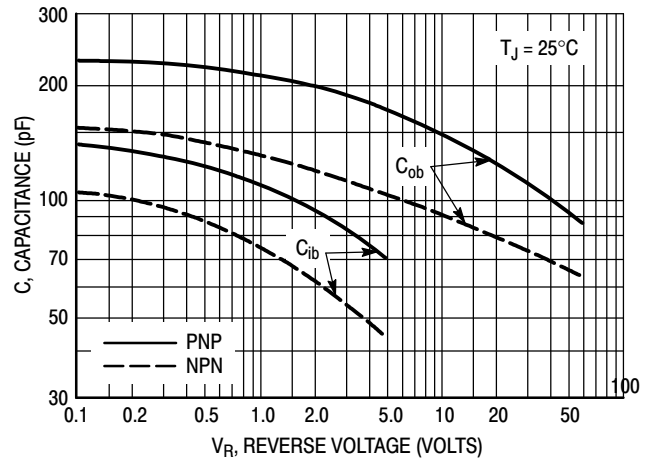
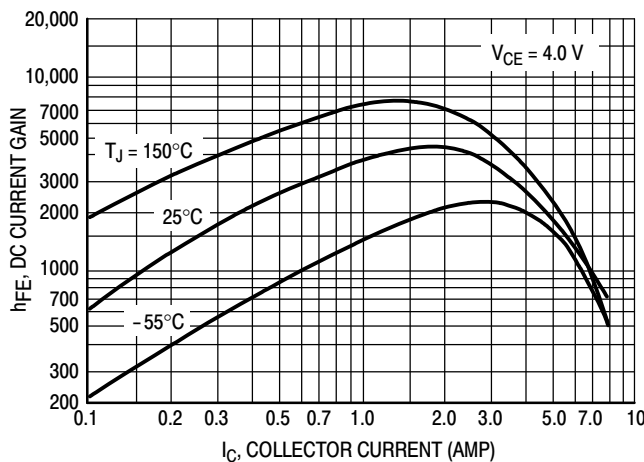


Figure 7. Capacitance

### PNP 2N6040, 2N6042



### NPN 2N6043, 2N6045

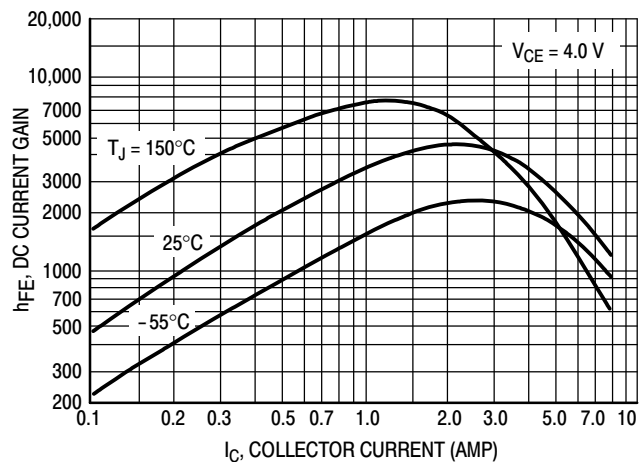


Figure 8. DC Current Gain

# PNP – 2N6040, 2N6042, NPN – 2N6043, 2N6045

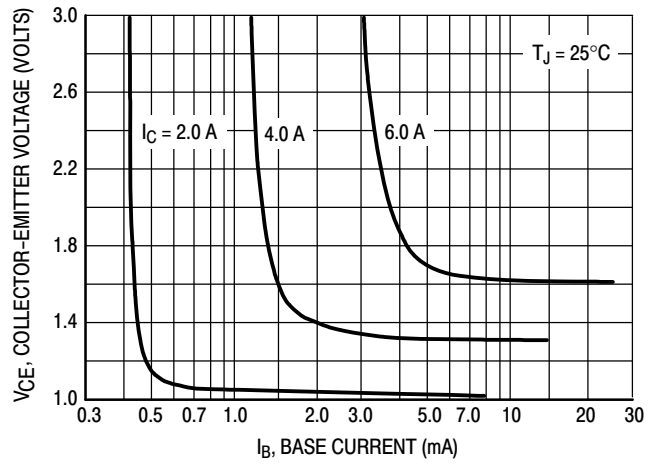
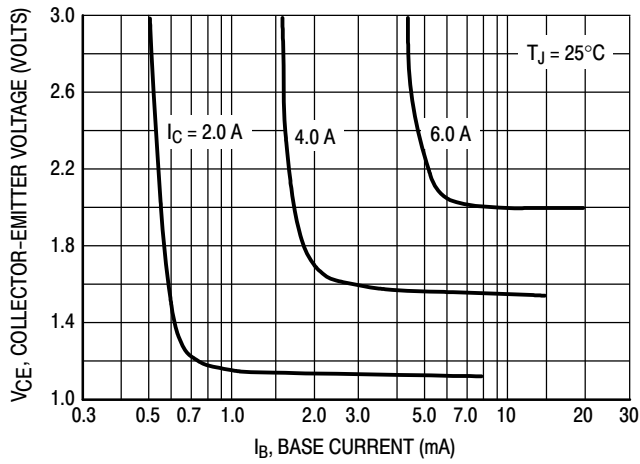


Figure 9. Collector Saturation Region

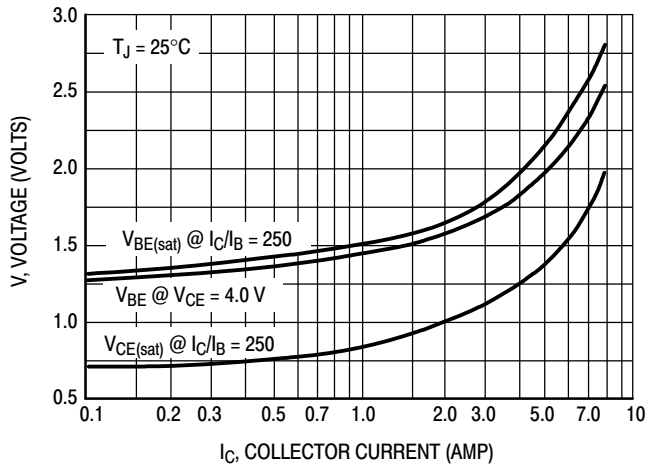
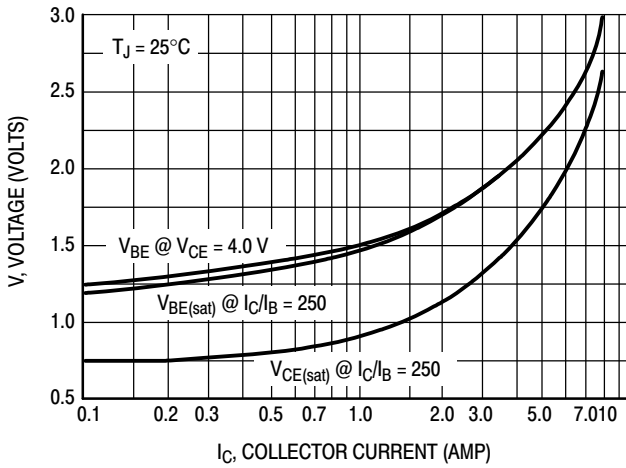


Figure 10. "On" Voltages

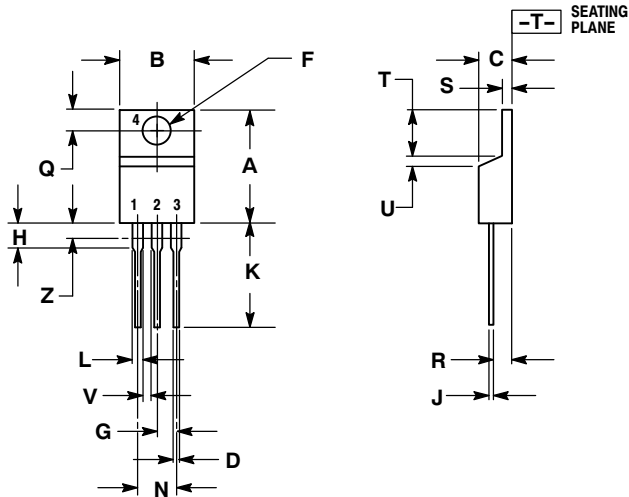
## ORDERING INFORMATION

Device	Package	Shipping
2N6040	TO-220AB	50 Units / Rail
2N6040G	TO-220AB (Pb-Free)	
2N6042	TO-220AB	
2N6042G	TO-220AB (Pb-Free)	
2N6043	TO-220AB	
2N6043G	TO-220AB (Pb-Free)	
2N6045	TO-220AB	
2N6045G	TO-220AB (Pb-Free)	

# PNP – 2N6040, 2N6042, NPN – 2N6043, 2N6045

## PACKAGE DIMENSIONS


### TO-220 CASE 221A-09 ISSUE AE



#### NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. DIMENSION Z DEFINES A ZONE WHERE ALL BODY AND LEAD IRREGULARITIES ARE ALLOWED.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.570	0.620	14.48	15.75
B	0.380	0.405	9.66	10.28
C	0.160	0.190	4.07	4.82
D	0.025	0.035	0.64	0.88
F	0.142	0.161	3.61	4.09
G	0.095	0.105	2.42	2.66
H	0.110	0.155	2.80	3.93
J	0.014	0.025	0.36	0.64
K	0.500	0.562	12.70	14.27
L	0.045	0.060	1.15	1.52
N	0.190	0.210	4.83	5.33
Q	0.100	0.120	2.54	3.04
R	0.080	0.110	2.04	2.79
S	0.045	0.055	1.15	1.39
T	0.235	0.255	5.97	6.47
U	0.000	0.050	0.00	1.27
V	0.045	---	1.15	---
Z	---	0.080	---	2.04

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